

# NLAS4053

## Analog Multiplexer/ Demultiplexer

### Triple 2:1 Analog Switch–Multiplexer Improved Process, Sub–Micron Silicon Gate CMOS

The NLAS4053 is an improved version of the MC14053 and MC74HC4053 fabricated in sub–micron Silicon Gate CMOS technology for lower  $R_{DS(on)}$  resistance and improved linearity with low current. This device may be operated either with a single supply or dual supply up to  $\pm 3.0$  V to pass a 6 V<sub>PP</sub> signal without coupling capacitors.

When operating in single supply mode, it is only necessary to tie V<sub>EE</sub>, pin 7 to ground. For dual supply operation, V<sub>EE</sub> is tied to a negative voltage, not to exceed maximum ratings. Pin for pin compatible with all industry standard versions of '4053.'

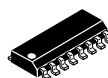
#### Features

- Improved  $R_{DS(on)}$  Specifications
- Pin for Pin Replacement for MAX4053 and MAX4053A
  - One Half the Resistance Operating at 5.0 Volts
- Single or Dual Supply Operation
  - Single 3–5 Volt Operation, or Dual  $\pm 3.0$  Volt Operation
  - With V<sub>CC</sub> of 3.0 to 3.3 V, Device Can Interface with 1.8 V Logic, No Translators Needed
  - Address and Inhibit Pins are Over–Voltage Tolerant and May Be Driven Up +6.0 V Regardless of V<sub>CC</sub>
  - Greatly Improved Noise Margin Over MAX4053 and MAX4053A
- Improved Linearity Over Standard HC4053 Devices
- Popular SOIC and the Space Saving TSSOP Packages
- Pb–Free Packages are Available\*

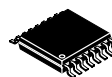
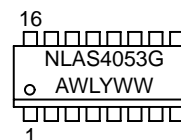


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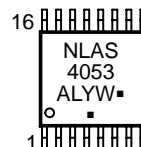
#### MARKING DIAGRAMS



SOIC–16  
D SUFFIX  
CASE 751B



TSSOP–16  
DT SUFFIX  
CASE 948F



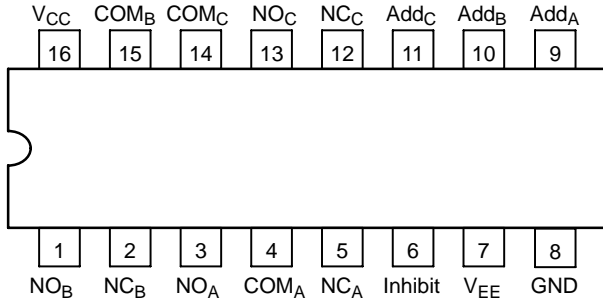
A = Assembly Location  
L, WL = Wafer Lot  
Y = Year  
W, WW = Work Week  
G = Pb–Free Package  
▪ = Pb–Free Package  
(Note: Microdot may be in either location)

#### ORDERING INFORMATION

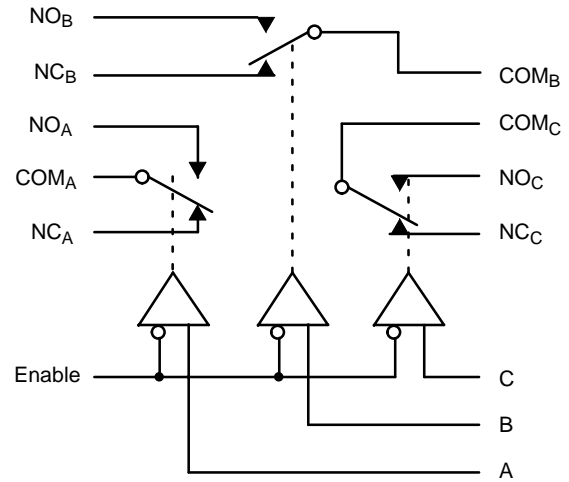
See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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**Figure 1. Pin Connection**  
(Top View)



**Figure 2. Logic Diagram**

## TRUTH TABLE

Inhibit	Address			ON SWITCHES*
	C	B	A	
1	X don't care	X don't care	X don't care	All switches open
0	0	0	0	COM <sub>A</sub> -NC <sub>A</sub> , COM <sub>B</sub> -NC <sub>B</sub> , COM <sub>C</sub> -NC <sub>C</sub>
0	0	0	1	COM <sub>A</sub> -NO <sub>A</sub> , COM <sub>B</sub> -NC <sub>B</sub> , COM <sub>C</sub> -NC <sub>C</sub>
0	0	1	0	COM <sub>A</sub> -NC <sub>A</sub> , COM <sub>B</sub> -NO <sub>B</sub> , COM <sub>C</sub> -NC <sub>C</sub>
0	0	1	1	COM <sub>A</sub> -NO <sub>A</sub> , COM <sub>B</sub> -NO <sub>B</sub> , COM <sub>C</sub> -NC <sub>C</sub>
0	1	0	0	COM <sub>A</sub> -NC <sub>A</sub> , COM <sub>B</sub> -NC <sub>B</sub> , COM <sub>C</sub> -NO <sub>C</sub>
0	1	0	1	COM <sub>A</sub> -NO <sub>A</sub> , COM <sub>B</sub> -NC <sub>B</sub> , COM <sub>C</sub> -NO <sub>C</sub>
0	1	1	0	COM <sub>A</sub> -NC <sub>A</sub> , COM <sub>B</sub> -NO <sub>B</sub> , COM <sub>C</sub> -NO <sub>C</sub>
0	1	1	1	COM <sub>A</sub> -NO <sub>A</sub> , COM <sub>B</sub> -NO <sub>B</sub> , COM <sub>C</sub> -NO <sub>C</sub>

\*NO, NC, and COM pins are identical and interchangeable. Either may be considered an input or output; signals pass equally well in either direction.

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## MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{EE}$	Negative DC Supply Voltage (Referenced to GND)	-7.0 to +0.5	V
$V_{CC}$	Positive DC Supply Voltage (Note 1) (Referenced to GND) (Referenced to $V_{EE}$ )	-0.5 to +7.0 -0.5 to +7.0	V
$V_{IS}$	Analog Input Voltage	$V_{EE} - 0.5$ to $V_{CC} + 0.5$	V
$V_{IN}$	Digital Input Voltage (Referenced to GND)	-0.5 to 7.0	V
I	DC Current, Into or Out of Any Pin	± 50	mA
$T_{STG}$	Storage Temperature Range	-65 to +150	°C
$T_L$	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
$T_J$	Junction Temperature under Bias	+150	°C
$\theta_{JA}$	Thermal Resistance SOIC TSSOP	143 164	°C/W
$P_D$	Power Dissipation in Still Air, SOIC TSSOP	500 450	mW
MSL	Moisture Sensitivity	Level 1	
$F_R$	Flammability Rating Oxygen Index: 30% – 35%	UL 94 V-0 @ 0.125 in	
$V_{ESD}$	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 > 1000	V
$I_{LATCHUP}$	Latchup Performance Above $V_{CC}$ and Below GND at 125°C (Note 5)	± 300	mA

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. The absolute value of  $V_{CC} \pm |V_{EE}| \leq 7.0$ .
2. Tested to EIA/JESD22-A114-A.
3. Tested to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
$V_{EE}$	Negative DC Supply Voltage (Referenced to GND)	-5.5	GND	V
$V_{CC}$	Positive DC Supply Voltage (Referenced to GND) (Referenced to $V_{EE}$ )	2.5 2.5	5.5 6.6	V
$V_{IS}$	Analog Input Voltage	$V_{EE}$	$V_{CC}$	V
$V_{IN}$	Digital Input Voltage (Note 6) (Referenced to GND)	0	5.5	V
$T_A$	Operating Temperature Range, All Package Types	-55	125	°C
$t_r, t_f$	Input Rise/Fall Time (Channel Select or Enable Inputs) $V_{CC} = 3.0 V \pm 0.3 V$ $V_{CC} = 5.0 V \pm 0.5 V$	0 0	100 20	ns/V

6. Unused digital inputs may not be left open. All digital inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

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## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NLAS4053D	SOIC-16	48 Units / Rail
NLAS4053DG	SOIC-16 (Pb-Free)	48 Units / Rail
NLAS4053DR2	SOIC-16	2500 Tape & Reel
NLAS4053DR2G	SOIC-16 (Pb-Free)	2500 Tape & Reel
NLAS4053DT	TSSOP-16*	96 Units / Rail
NLAS4053DTG	TSSOP-16*	96 Units / Rail
NLAS4053DTR2	TSSOP-16*	2500 Tape & Reel
NLAS4053DTR2G	TSSOP-16*	2500 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*This package is inherently Pb-Free.

## DC CHARACTERISTICS – Digital Section (Voltages Referenced to GND)

Symbol	Parameter	Condition	V <sub>CC</sub> V	Guaranteed Limit			Unit
				-55 to 25°C	≤ 85°C	≤ 125°C	
V <sub>IH</sub>	Minimum High-Level Input Voltage, Address and Inhibit Inputs		2.0	1.5	1.5	1.5	V
			3.0	2.1	2.1	2.1	
			4.5	3.15	3.15	3.15	
			5.5	3.85	3.85	3.85	
V <sub>IL</sub>	Maximum Low-Level Input Voltage, Address and Inhibit Inputs		2.0	0.5	0.5	0.5	V
			3.0	0.9	0.9	0.9	
			4.5	1.35	1.35	1.35	
			5.5	1.65	1.65	1.65	
I <sub>IN</sub>	Maximum Input Leakage Current, Address or Inhibit Inputs	V <sub>IN</sub> = 6.0 or GND	0 V to 6.0 V	± 0.1	± 1.0	± 1.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	Channel Select, Enable and V <sub>IS</sub> = V <sub>CC</sub> or GND	6.0	4.0	40	80	μA

## DC ELECTRICAL CHARACTERISTICS – Analog Section

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	V <sub>EE</sub> V	Guaranteed Limit			Unit
					-55 to 25°C	≤ 85°C	≤ 125°C	
R <sub>ON</sub>	Maximum "ON" Resistance	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> V <sub>IS</sub> = V <sub>EE</sub> to V <sub>CC</sub>  I <sub>S</sub>   = 10 mA (Figures 4 thru 9)	3.0	0	86	108	120	Ω
			4.5	0	37	46	55	
			3.0	-3.0	26	33	37	
ΔR <sub>ON</sub>	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> , V <sub>IS</sub> = 2.0 V V <sub>IS</sub> = 3.5 V  I <sub>S</sub>   = 10 mA, V <sub>IS</sub> = 2.0 V	3.0	0	15	20	20	Ω
			4.5	0	13	18	18	
			3.0	-3.0	10	15	15	
R <sub>flat(ON)</sub>	COM-NO On-Resistance Flatness	V <sub>com</sub> 1, 2, 3.5 V V <sub>com</sub> -2, 0, 2 V  I <sub>S</sub>   = 10 mA	4.5 3.0	0 -3.0	4 2	4 2	5 3	Ω
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	Maximum Off-Channel Leakage Current	Switch Off V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> V <sub>IO</sub> = V <sub>CC</sub> -1.0 V or V <sub>EE</sub> +1.0 V (Figure 17)	6.0	0	0.1	5.0	100	nA
			3.0	-3.0	0.1	5.0	100	
I <sub>COM(ON)</sub>	Maximum On-Channel Leakage Current, Channel- to-Channel	Switch On V <sub>IO</sub> = V <sub>CC</sub> -1.0 V or V <sub>EE</sub> +1.0 V (Figure 17)	6.0	0	0.1	5.0	100	nA
			3.0	-3.0	0.1	5.0	100	

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## AC CHARACTERISTICS (Input $t_r = t_f = 3$ ns)

Symbol	Parameter	Test Conditions	$V_{CC}$ V	$V_{EE}$ V	Guaranteed Limit				Unit
					-55 to 25°C		≤ 85°C	≤ 125°C	
					Min	Typ*			
$t_{BMM}$	Minimum Break-Before-Make Time	$V_{IN} = V_{IL}$ or $V_{IH}$ $V_{IS} = V_{CC}$ $R_L = 300 \Omega$ , $C_L = 35$ pF (Figure 19)	3.0	0.0	1.0	6.5	–	–	ns
			4.5	0.0	1.0	5.0	–	–	
			3.0	-3.0	1.0	3.5	–	–	

\*Typical Characteristics are at 25°C.

## AC CHARACTERISTICS ( $C_L = 50$ pF, Input $t_r = t_f = 3$ ns)

Symbol	Parameter	$V_{CC}$ V	$V_{EE}$ V	Guaranteed Limit						Unit	
				-55 to 25°C			≤ 85°C		≤ 125°C		
				Min	Typ	Max	Min	Max	Min		Max
$t_{TRANS}$	Transition Time (Address Selection Time) (Figure 18)	2.5	0			40		45		50	ns
		3.0	0			28		30		35	
		4.5	0			23		25		30	
		3.0	-3.0			23		25		28	
$t_{ON}$	Turn-on Time (Figures 14, 15, 20, and 21) Enable to $N_O$ or $N_C$	2.5	0			40		45		50	ns
		3.0	0			28		30		35	
		4.5	0			23		25		30	
		3.0	-3.0			23		25		28	
$t_{OFF}$	Turn-off Time (Figures 14, 15, 20, and 21) Enable to $N_O$ or $N_C$	2.5	0			40		45		50	ns
		3.0	0			28		30		35	
		4.5	0			23		25		30	
		3.0	-3.0			23		25		28	

		Typical @ 25°C, $V_{CC} = 5.0$ V		
$C_{IN}$	Maximum Input Capacitance, Select Inputs	8		pF
$C_{NO}$ or $C_{NC}$	Analog I/O	10		
$C_{COM}$	Common I/O	10		
$C_{(ON)}$	Feedthrough	1.0		

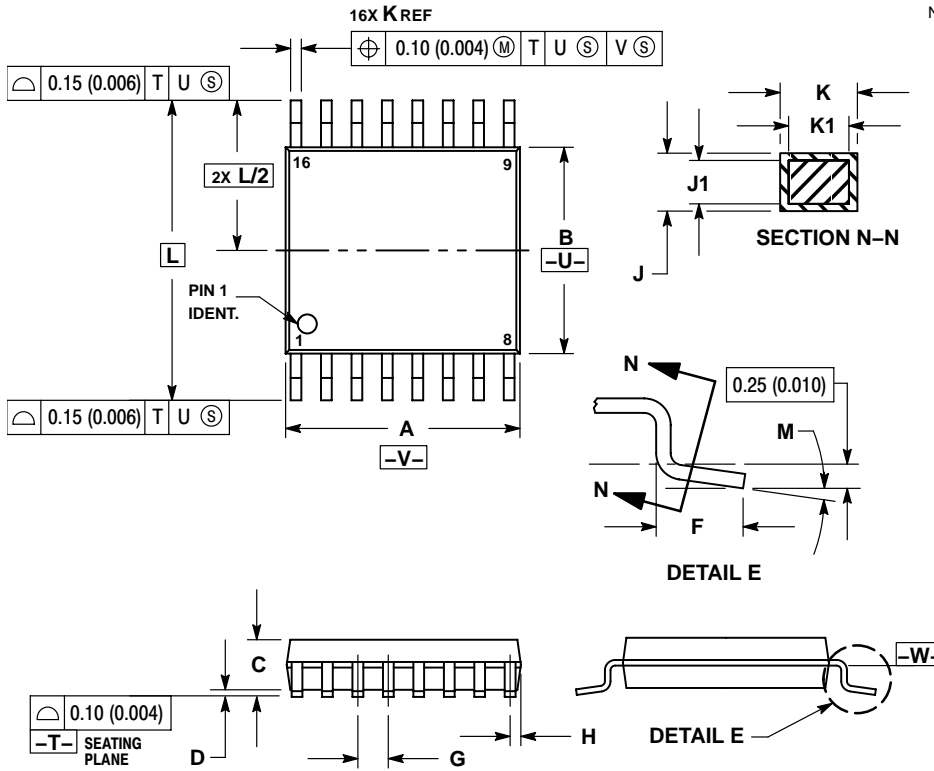
## ADDITIONAL APPLICATION CHARACTERISTICS (GND = 0 V)

Symbol	Parameter	Condition	$V_{CC}$ V	$V_{EE}$ V	Typ	Unit
					25°C	
BW	Maximum On-Channel Bandwidth or Minimum Frequency Response	$V_{IS} = \frac{1}{2}(V_{CC} - V_{EE})$ Source Amplitude = 0 dBm (Figures 10 and 22)	3.0	0.0	145	MHz
			4.5	0.0	165	
			6.0	0.0	180	
			3.0	-3.0	180	
$V_{ISO}$	Off-Channel Feedthrough Isolation	$f = 100$ kHz; $V_{IS} = \frac{1}{2}(V_{CC} - V_{EE})$ Source = 0 dBm (Figures 12 and 22)	3.0	0.0	-93	dB
			4.5	0.0	-93	
			6.0	0.0	-93	
			3.0	-3.0	-93	
$V_{ONL}$	Maximum Feedthrough On Loss	$V_{IS} = \frac{1}{2}(V_{CC} - V_{EE})$ Source = 0 dBm (Figures 10 and 22)	3.0	0.0	-2	dB
			4.5	0.0	-2	
			6.0	0.0	-2	
			3.0	-3.0	-2	
Q	Charge Injection	$V_{IN} = V_{CC}$ to $V_{EE}$ , $f_{IS} = 1$ kHz, $t_r = t_f = 3$ ns $R_{IS} = 0 \Omega$ , $C_L = 1000$ pF, $Q = C_L * \Delta V_{OUT}$ (Figures 16 and 23)	5.0	0.0	9.0	pC
			3.0	-3.0	12	
THD	Total Harmonic Distortion THD + Noise	$f_{IS} = 1$ MHz, $R_L = 10$ K $\Omega$ , $C_L = 50$ pF, $V_{IS} = 5.0$ V <sub>PP</sub> sine wave $V_{IS} = 6.0$ V <sub>PP</sub> sine wave (Figure 13)	6.0	0.0	0.10	%
			3.0	-3.0	0.05	

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## PACKAGE DIMENSIONS

TSSOP-16  
DT SUFFIX  
CASE 948F-01  
ISSUE A



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°